NSN 5961-00-919-5885

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View Online at https://aerobasegroup.com/nsn/5961-00-919-5885 **Inclosure Material:** Metal **Overall Length:** 0.215 inches **Overall Diameter:** 0.460 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.138 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 10.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 500.00 milliamperes source cutoff current and 750.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release3379 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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